TOSHIBA CMOS Digital Integrated Circuit   Silicon Monolithic

TC7MB3257FK

Quad 1-of-2 Multiplexer/Demultiplexer

The TC7MB3257FK is high-speed CMOS quad 1-2 multiplexer/demultiplexer. The low on resistance of the switch allows connections to be made with minimal propagation delay time.

This device consists of four individual two-inputs multiplexer/demultiplexer with common select input (S) and output enable ($\overline{OE}$). The A inputs is connected to the B1 or B2 outputs determined by the combination both the select input (S) and output enable ($\overline{OE}$). When the output enable ($\overline{OE}$) input is held "H" level, the switches are open with regardless the state of select inputs and a high-impedance state exists between the switches.

All inputs are equipped with protection circuits against static discharge.
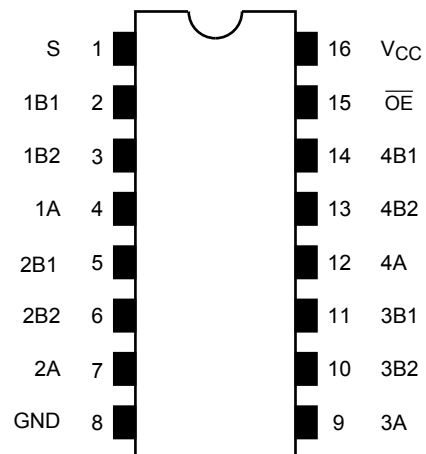

VSSOP16-P-0030-0.50
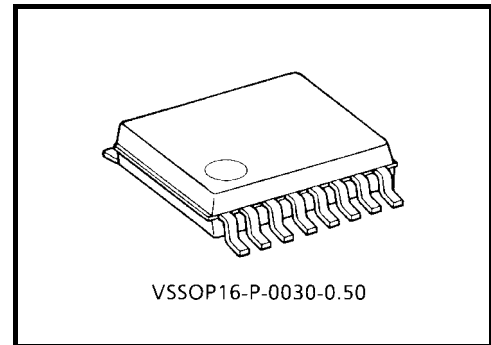
Weight: 0.02 g (typ.)

Features

- Operating voltage: V_{CC} = 4.5~5.5 V
- High speed: t_{pd} = 0.25 ns (max)
- Low on resistance: R_{ON} = 5 Ω (typ.)
- ESD performance: Machine model ≥ ±200 V
  Human body model ≥ ±2000 V
- Compatible with TTL outputs (control inputs)
- Package: VSSOP (US16)
- Pin compatible with the 74xx257 type.
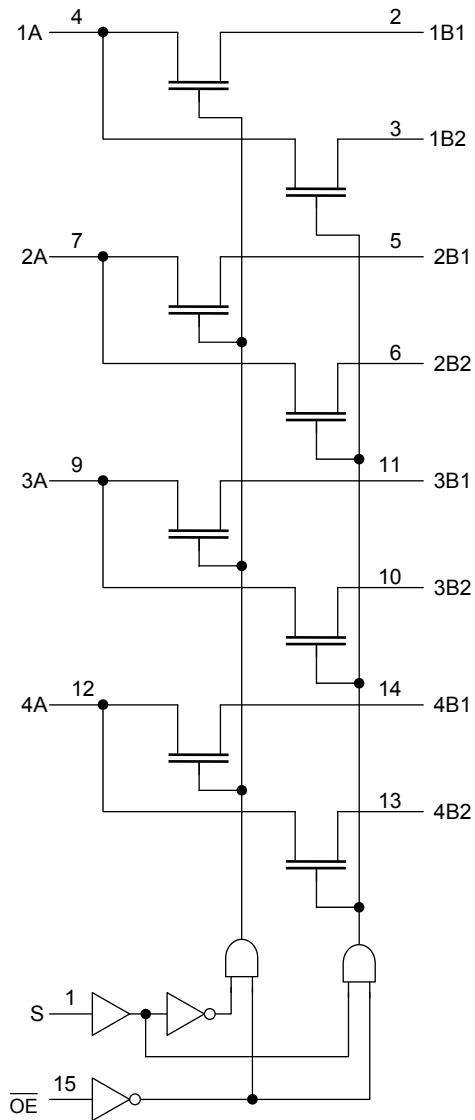 Functionally equivalent to (FST/CBT) 3257.

Pin Assignment (top view)

S	1		16	V_{CC}
1B1	2		15	$\overline{OE}$
1B2	3		14	4B1
1A	4		13	4B2
2B1	5		12	4A
2B2	6		11	3B1
2A	7		10	3B2
GND	8		9	3A

Truth Table

Inputs		Function
$\overline{OE}$	S	
L	L	A port = B1 port
L	H	A port = B2 port
H	X	Disconnect

System Diagram

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Power supply range	V_{CC}	−0.5~7.0	V
DC input voltage	V_{IN}	−0.5~7.0	V
DC switch voltage	V_S	−0.5~7.0	V
Input diode current	I_{IK}	−50	mA
Continuous channel current	I_S	128	mA
Power dissipation	P_D	180	mW
DC V_{CC}/GND current	I_{CC}/I_{GND}	±100	mA
Storage temperature	T_{stg}	−65~150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	4.5~5.5	V
Input voltage	V_{IN}	0~5.5	V
Switch voltage	V_S	0~5.5	V
Operating temperature	T_{opr}	−40~85	°C
Input rise and fall time	dt/dv	0~10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics (Ta = −40~85°C)

Characteristics		Symbol	Test Condition		V$_{CC}$ (V)	Min	Typ. (Note 1)	Max	Unit
Input voltage	"H" level	V$_{IH}$	—		4.5~5.5	2.0	—	—	V
	"L" level	V$_{IL}$	—		4.5~5.5	—	—	0.8	
Input leakage current ($\overline{OE}$, S)		I$_{IN}$	V$_{IN}$ = 0~5.5 V		4.5~5.5	—	—	±1.0	μA
Power off leakage current		I$_{OFF}$	A, B, $\overline{OE}$ = 0~5.5 V		0	—	—	±1.0	μA
Off-state leakage current (switch off)		I$_{SZ}$	A, B = 0~5.5 V, $\overline{OE}$ = V$_{CC}$		4.5~5.5	—	—	±1.0	μA
ON resistance (Note 2)		R$_{ON}$	V$_{IS}$ = 0 V	I$_{IS}$ = 64 mA	4.5	—	5	7	Ω
				I$_{IS}$ = 30 mA	4.5	—	5	7	
			V$_{IS}$ = 2.4 V, I$_{IS}$ = 15 mA		4.5	—	10	15	
Increase in I$_{CC}$ per input		I$_{CC}$	V$_{IN}$ = V$_{CC}$ or GND, I$_{OUT}$ = 0		5.5	—	—	10	μA
		ΔI$_{CC}$	V$_{IN}$ = 3.4 V (one input)		5.5	—	—	2.5	mA

Note 1:   Typical values are at V$_{CC}$ = 5 V, Ta = 25°C.

Note 2:   Measured by the voltage drop between A and B pins at the indicated current through the switch.
ON resistance is determined by the lower of the voltages on the two (A or B) pins.

AC Characteristics (Ta = −40~85°C)

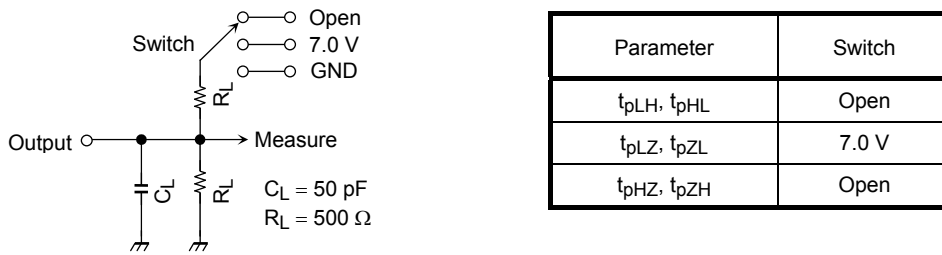| Characteristics	Symbol	Test Condition		V$_{CC}$ (V)	Min	Max	Unit
Propagation delay time (bus to bus)	t$_{pLH}$ t$_{pHL}$	Figure 1, Figure 2	(Note)	4.5	—	0.25	ns
Propagation delay time (S to bus)	t$_{pLH}$ t$_{pHL}$	Figure 1, Figure 2		4.5	—	5.0	ns
Output enable time ($\overline{OE}$ to bus)	t$_{pZL}$ t$_{pZH}$	Figure 1, Figure 3		4.5	—	5.5	ns
Output enable time (S to bus)	t$_{pZL}$ t$_{pZH}$	Figure 1, Figure 3		4.5	—	5.5	ns
Output disable time ($\overline{OE}$ to bus)	t$_{pLZ}$ t$_{pHZ}$	Figure 1, Figure 3		4.5	—	5.0	ns
Output disable time (S to bus)	t$_{pLZ}$ t$_{pHZ}$	Figure 1, Figure 3		4.5	—	5.0	ns

Note: This parameter is guaranteed by design but is not tested. The bus switch contributes no propagation delay other than the RC delay of the typical on resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage the source (zero output impedance).

Capacitive Characteristics (Ta = 25°C)

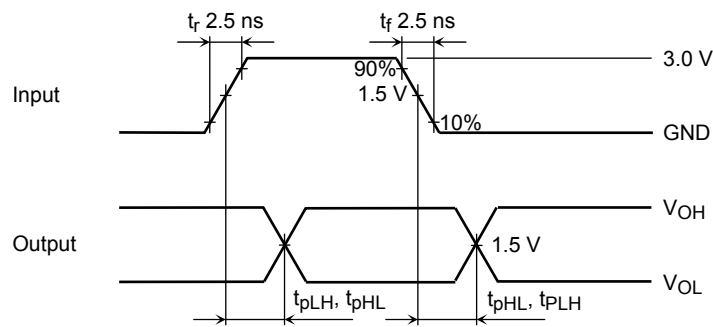| Characteristics	Symbol	Test Condition		V$_{CC}$ (V)	Typ.	Unit
Control pin input capacitance ($\overline{OE}$, S)	C$_{IN}$		(Note)	5.0	3	pF
Switch terminal capacitance (B1~2)	C$_{I/O}$	$\overline{OE}$ = V$_{CC}$	(Note)	5.0	10	pF
Switch terminal capacitance (A)	C$_{I/O}$	$\overline{OE}$ = V$_{CC}$	(Note)	5.0	17	pF

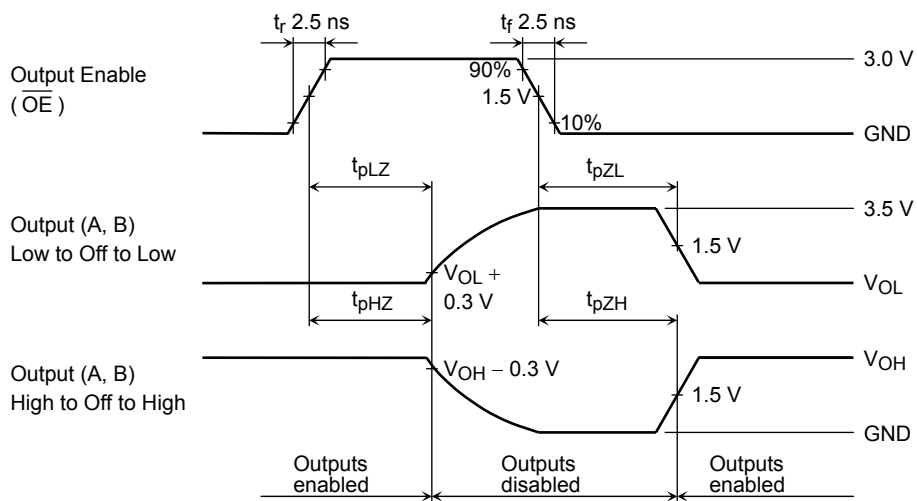Note: This parameter is guaranteed by design.

AC Test Circuit

Figure 1

Parameter	Switch
t_{pLH}, t_{pHL}	Open
t_{pLZ}, t_{pZL}	7.0 V
t_{pHZ}, t_{pZH}	Open

$C_L = 50$ pF
$R_L = 500$ Ω

AC Waveform

Figure 2 t_{pLH}, t_{pHL}

Figure 3 t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}

Package Dimensions
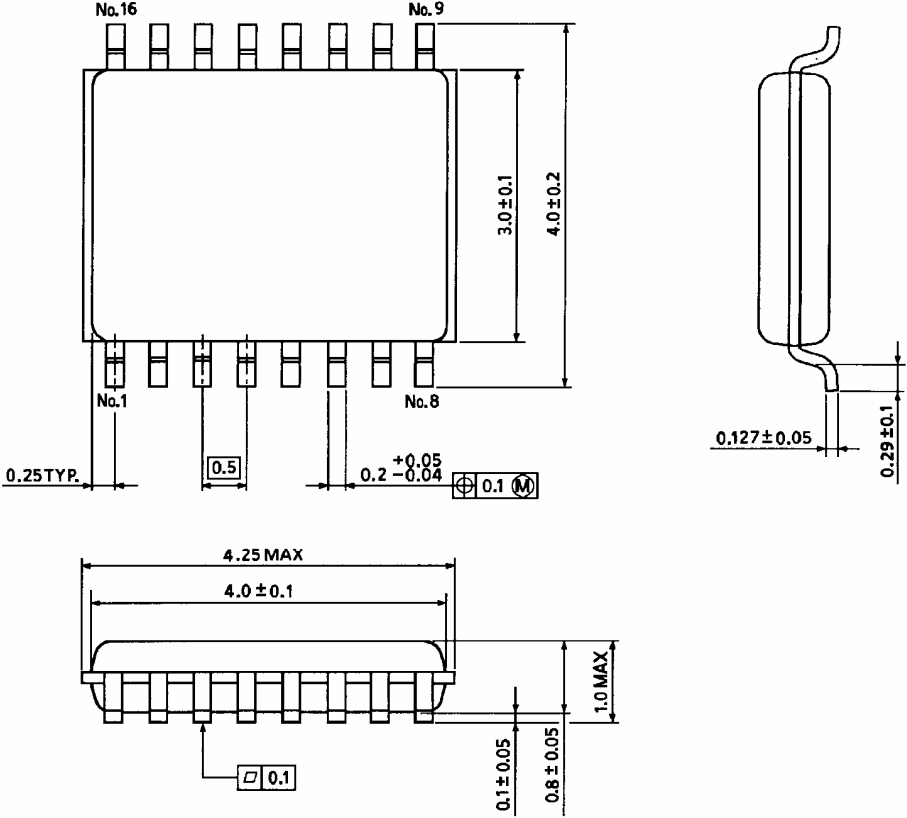
Weight: 0.02 g (typ.)

RESTRICTIONS ON PRODUCT USE